

# MOS FIELD EFFECT TRANSISTOR 2SK3404

# SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

## DESCRIPTION

The 2SK3404 is N-Channel MOS FET device that features a low on-state resistance and excellent switching characteristics, designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

## ORDERING INFORMATION

PART NUMBER	PACKAGE			
2SK3404	TO-220AB			
2SK3404-ZK	TO-263(MP-25ZK)			
2SK3404-ZJ	TO-263(MP-25ZJ)			

## FEATURES

- 4.5-V drive available
- Low on-state resistance  $R_{DS(on)1} = 14 \ m\Omega \ MAX. \ (V_{GS} = 10 \ V, \ I_D = 20 \ A)$
- Low gate charge
   Q<sub>G</sub> = 25 nC TYP. (I<sub>D</sub> = 40 A, V<sub>DD</sub> = 24 V, V<sub>GS</sub> = 10 V)
- Built-in gate protection diode
- Surface mount device available

## ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	Vdss	30	V
Gate to Source Voltage (VDs = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±40	А
Drain Current (Pulse) Note	D(pulse)	±160	А
Total Power Dissipation (T <sub>A</sub> = 25°C)	P <sub>T1</sub>	1.5	W
Total Power Dissipation (Tc = 25°C)	P <sub>T2</sub>	40	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C

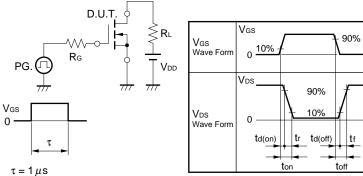
**Note** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

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# ELECTRICAL CHARACTERISTICS(TA = 25°C)

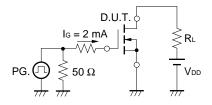
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Leakage Current	loss	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			10	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μΑ
Gate to Source Cut-off Voltage	VGS(off)	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.5		2.5	V
Forward Transfer Admittance	y <sub>fs</sub>	VDS = 10 V, ID = 20 A	8.0			S
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, Id = 20 A		11	14	mΩ
	RDS(on)2	Vgs = 4.5 V, Id = 20 A		15	21	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V		1400		pF
Output Capacitance	Coss	Vgs = 0 V		410		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		180		pF
Turn-on Delay Time	td(on)	Vdd = 15 V , Id = 20 A		20		ns
Rise Time	tr	VGS(on) = 10 V		9		ns
Turn-off Delay Time	td(off)	R <sub>G</sub> = 10 Ω		50		ns
Fall Time	tr			14		ns
Total Gate Charge	QG	V <sub>DD</sub> = 24 V		25		nC
Gate to Source Charge	QGS	Vgs = 10 V		5.0		nC
Gate to Drain Charge	Qgd	I <sub>D</sub> = 40 A		7.0		nC
Diode Forward Voltage	VF(S-D)	IF = 40 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 40 A, VGS = 0 V		31		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/µs		28		nC

## **TEST CIRCUIT 1 SWITCHING TIME**



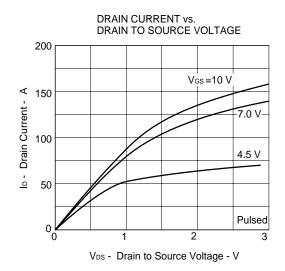
# Duty Cycle $\leq 1\%$

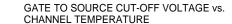
## **TEST CIRCUIT 2 GATE CHARGE**

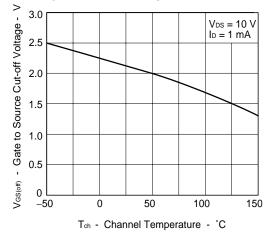


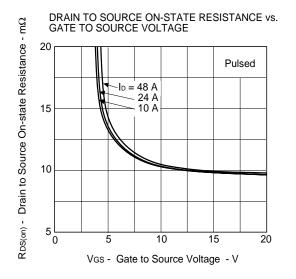
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# TYPICAL CHARACTERISTICS (TA = 25°C)

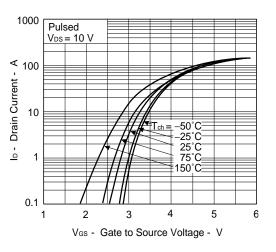




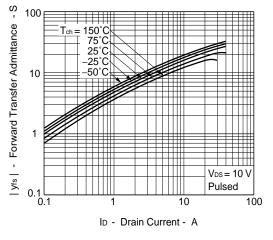


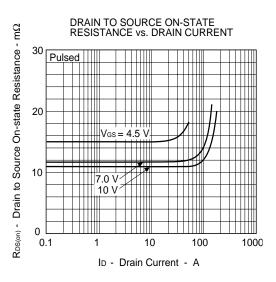


FORWARD TRANSFER CHARACTERISTICS

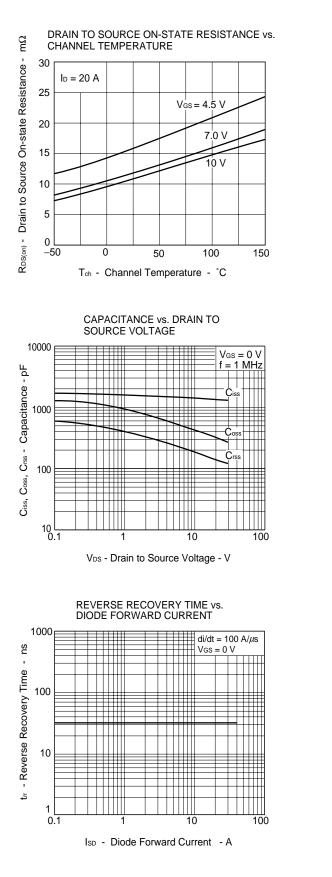


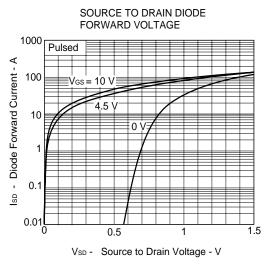
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



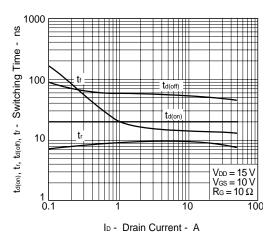


Data Sheet D14638EJ2V0DS

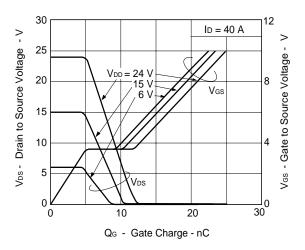




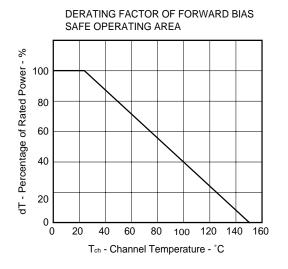
SWITCHING CHARACTERISTICS



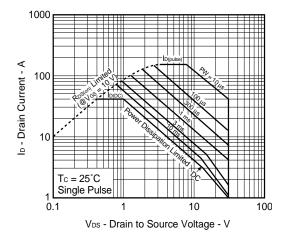
DYNAMIC INPUT/OUTPUT CHARACTERISTICS

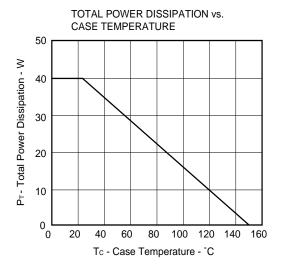


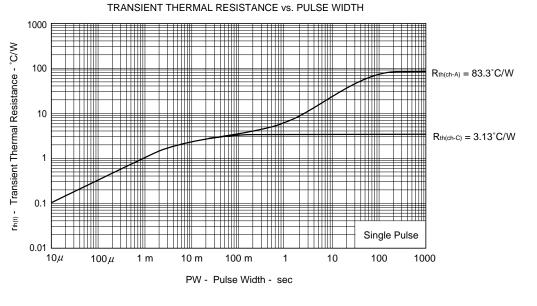
Data Sheet D14638EJ2V0DS



FORWARD BIAS SAFE OPERATING AREA



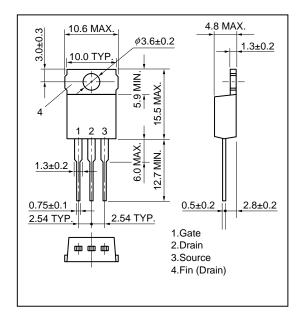




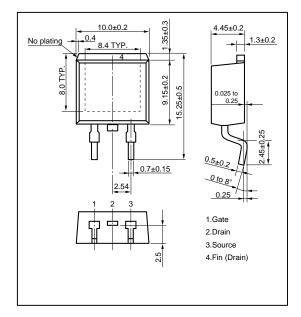
Data Sheet D14638EJ2V0DS

## PACKAGE DRAWINGS (Unit : mm)

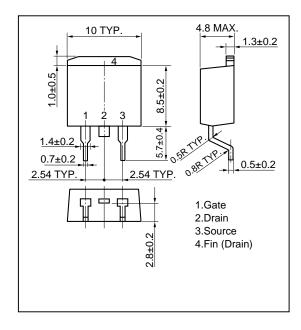
## ★ 1)TO-220AB (MP-25)



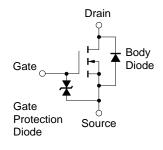
#### 2)TO-263 (MP-25ZK)



### \* 3)TO-263 (MP-25ZJ)



## EQUIVALENT CIRCUIT



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device. [MEMO]

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